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XP132A1275SR

ETR1108_001

Power MOSFET

GENERAL DESCRIPTION

The XP132A1275SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy. The small SOP-8 package makes high density mounting possible.

■ APPLICATIONS

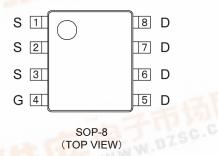
- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems



Low On-State Resistance : $Rds(on)=0.075\Omega$ (Vgs=-4.5V) : $Rds(on)=0.115\Omega$ (Vgs=-2.5V)

Switching
: -2.5V
MOSFET
: SOP-8

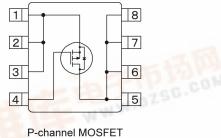
PIN CONFIGURATION



PIN ASSIGNMENT

	PIN NUMBER	PIN NAME	FUNCTION
	1~3	S	Source
	4	G	Gate
5~8		D	Drain
	11111		

EQUIVALENT CIRCUIT



P<mark>-channel MOSFE</mark>1 (1 device built-in)

ABSOLUTE MAXIMUM RATINGS

Ta = 25						
PARAMETER	SYMBOL	RATINGS	UNITS			
Drain-Source Voltage	Vdss	-20	V			
Gate-Source Voltage	Vgss	±12	V			
Drain Current (DC)	ld	-5	А			
Drain Current (Pulse)	ldp	-20	А			
Reverse Drain Current	ldr	-5	А			
Channel Power Dissipation *	Pd	2.5	W			
Channel Temperature	Tch	150	°C			
Storage Temperature Range	Tstg	-55~150	°C			

* When implemented on a glass epoxy PCB



XP132A1275SR

■ ELECTRICAL CHARACTERISTICS

DC Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=-20V, Vgs=0V	-	-	-10	μA
Gate-Source Leak Current	lgss	Vgs=±12V, Vds=0V	-	-	±1	μA
Gate-Source Cut-Off Voltage	Vgs(off)	Id=-1mA, Vds=-10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *	Rds(on)	Id=-3A, Vgs=-4.5V	-	0.06	0.075	Ω
	Rus(UII)	Id=-3A, Vgs=-2.5V	-	0.092	0.115	Ω
Forward Transfer Admittance *	Yfs	Id=-3A, Vds=-10V	-	8	-	S
Body Drain Diode Forward Voltage	Vf	lf=-5A, Vgs=0V	-	-0.85	-1.1	V

* Effective during pulse test.

Dynamic Characteristics

Dynamic CharacteristicsTa = 25°C						
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=-10V, Vgs=0V f=1MHz	-	770	-	pF
Output Capacitance	Coss		-	440	-	pF
Feedback Capacitance	Crss		-	180	-	pF

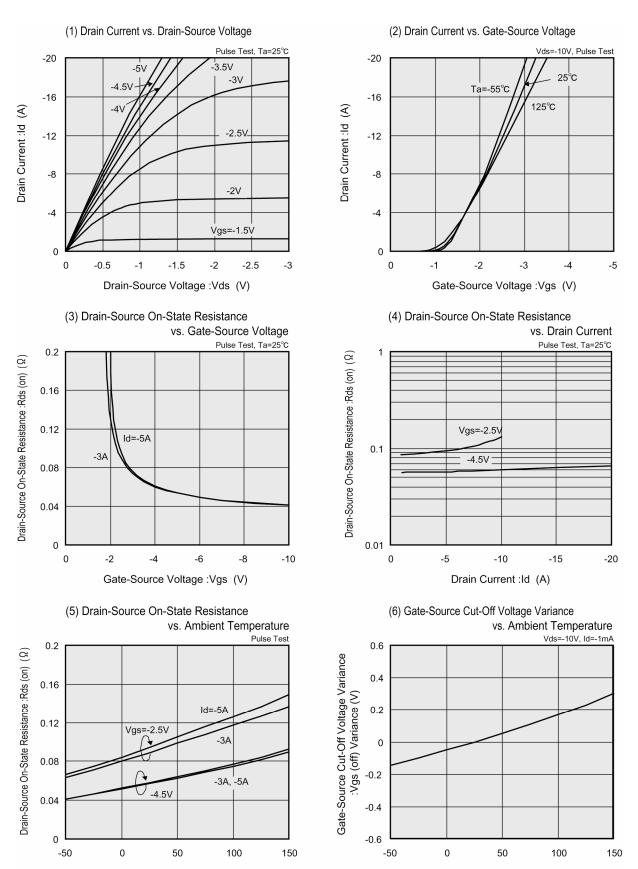
Switching Characteristics

0						u 200
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=-5V, Id=-3A Vdd=-10V	-	10	-	ns
Rise Time	tr		-	25	-	ns
Turn-Off Delay Time	td (off)		-	45	-	ns
Fall Time	tf		-	40	-	ns

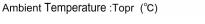
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

Ta = 25°C



■TYPICAL PERFORMANCE CHARACTERISTICS



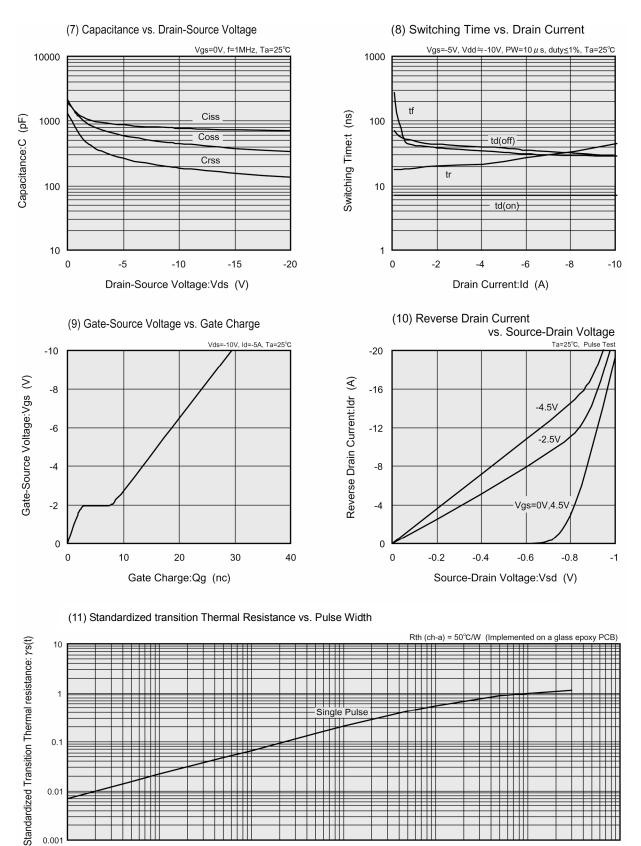
Ambient Temperature :Topr (°C)

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0.01

0.001 0.0001

■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



0.1 Pulse Width: PW (sec)

1

0.01

0.001

10

100

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